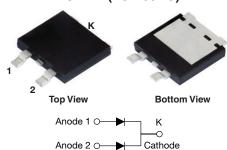


Hyperfast Rectifier, 2 x 8 A FRED Pt®





LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | |
|----------------------------------|-----------------|--|--|--|
| I _{F(AV)} | 2 x 8 A | | | |
| V _R | 200 V | | | |
| V _F at I _F | 0.77 V | | | |
| t _{rr} | 27 ns | | | |
| T _J max. | 175 °C | | | |
| Package | SMPD (TO-263AC) | | | |
| Circuit configuration | Common cathode | | | |

FEATURES

 \bullet Hyperfast recovery time, reduced $\mathsf{Q}_{\text{rr}},$ and soft recovery



• 175 °C maximum operating junction temperature

• Specified for output and snubber operation

COMPLIANT HALOGEN FREE

Low forward voltage drop

· Low leakage current

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, telecom, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per

J-STD-002

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|------------|----------------------------------|--|--------|-------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Peak repetitive reverse voltage | | V_{RRM} | | 200 | V |
| Average rectified forward current per device per diode | per device | | T 155 °C | 16 | 1 |
| | IF(AV) | T _{solder pad} = 155 °C | 8 | ^ | |
| Non repetitive peak curse current | per device | | T _{.1} = 25 °C, 6 ms square pulse | 190 | A |
| Non-repetitive peak surge current per diode | | IFSM | IJ = 25 C, O IIIS Square puise | 100 | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|---|--|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage | V_{BR} , V_{R} | $I_R = 100 \mu A$ | 200 | - | - | |
| Forward voltage, per diode V _F | W | I _F = 8 A | - | 0.93 | 1.03 | V |
| | I _F = 8 A, T _J = 150 °C | - | 0.77 | 0.87 | | |
| Reverse leakage current, per diode I _R | | $V_R = V_R$ rated | - | = | 2 | |
| | ЧR | T _J = 150 °C, V _R = V _R rated | - | 6 | 100 | μΑ |
| Junction capacitance, per diode | C _T | V _R = 200 V | - | 23 | - | pF |



| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified) | | | | | | | |
|---|------------------------|--|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| | | $I_F = 1 A, dI_F/dt = 50 A$ | /μs, V _R = 30 V | - | 27 | - | |
| Reverse recovery time t _{rr} | | I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A | | - | - | 25 | 1 |
| | L _{rr} | T _J = 25 °C | | - | 23 | - | ns |
| | | T _J = 125 °C | $I_F = 8 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s},$ $V_B = 160 \text{ V}$ | =. | 35 | - | |
| Dook roopyony gurrent | 1 | T _J = 25 °C | | - | 2.8 | - | ^ |
| Peak recovery current | I _{RRM} | $T_{J} = 125 ^{\circ}\text{C}$ $V_{B} = 160 \text{V}$ - | | 5 | - | Α | |
| Poverse recovery charge | T _J = 25 °C | | - | 30 | - | nC | |
| Reverse recovery charge | Q_{rr} | T _J = 125 °C | | - | 90 | - | IIC |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|---|-----------------------------------|----------------------------|---------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | +175 | °C |
| Thermal resistance, per diode junction to mount | R_{thJM} | | - | 1.8 | 2.5 | °C/W |
| Approximate weight | | | | 0.55 | | g |
| Approximate weight | | | | 0.02 | | oz. |
| Marking device | | Case style SMPD (TO-263AC) | 16CDH02 | | | |

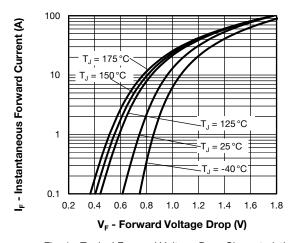


Fig. 1 - Typical Forward Voltage Drop Characteristics

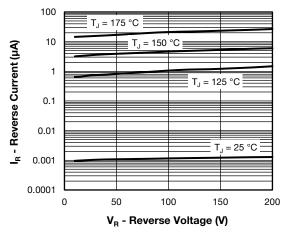


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

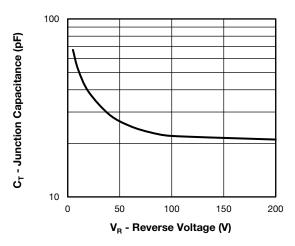


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

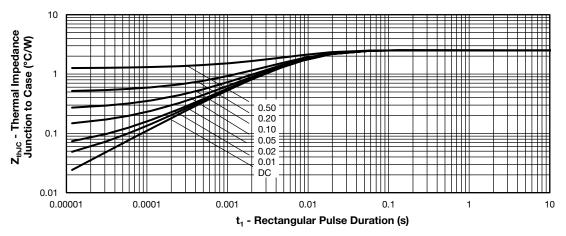


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

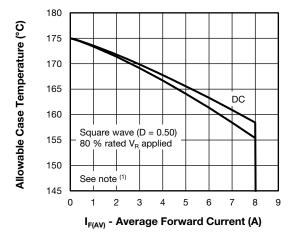


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

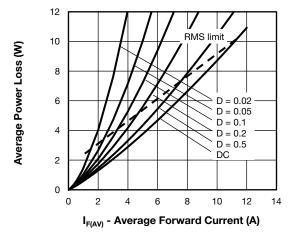


Fig. 6 - Forward Power Loss Characteristics

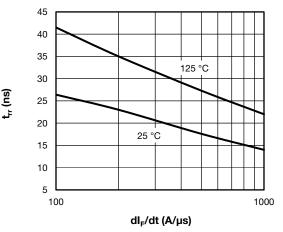
Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 5); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = rated V_R$



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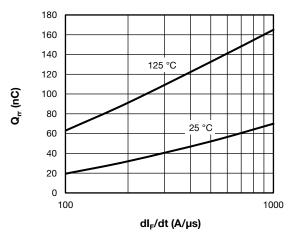
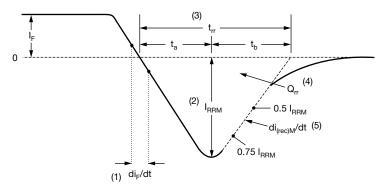


Fig. 8 - Typical Stored Charge vs. dl_E/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

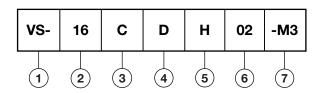
(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (16 A)

Circuit configuration:

C = common cathode

4 - D = SMPD package

5 - Process type,

H = hyperfast recovery

6 - Voltage code (02 = 200 V)

7 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

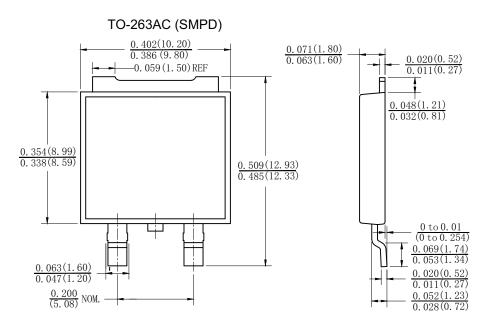
| ORDERING INFORMATION (Example) | | | | | | |
|--|------|------|------------------------------------|--|--|--|
| PREFERRED P/N QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION | | | | | | |
| VS-16CDH02-M3/I | 2000 | 2000 | 13" diameter plastic tape and reel | | | |

| LINKS TO RELATED DOCUMENTS | | | | |
|----------------------------|--------------------------|--|--|--|
| Dimensions | www.vishay.com/doc?95604 | | | |
| Part marking information | www.vishay.com/doc?95566 | | | |
| Packaging information | www.vishay.com/doc?88869 | | | |

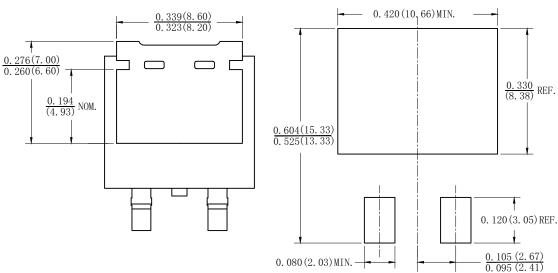


TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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